

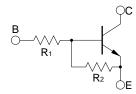
SILICON TRANSISTOR

FA1A4M

MEDIUM SPEED SWITCHING RESISTOR BUILT-IN TYPE NPN TRANSISTOR MINI MOLD

FEATURES

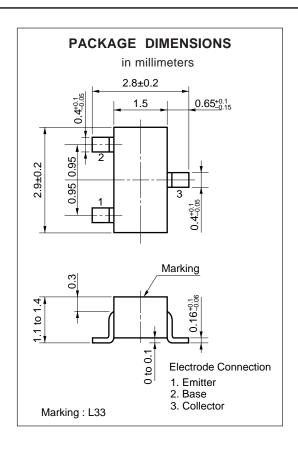
• Resistors Built-in TYPE



· Complementary to FN1A4M

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

Collector to Base Voltage	Vсво	60	V
Collector to Emitter Voltage	Vceo	50	V
Emitter to Base Voltage	Vево	10	V
Collector Current (DC)	Ic	100	mΑ
Collector Current (Pulse)	Ic	200	mΑ
Total Power Dissipation	Рт	200	mW
$(T_A = 25 \degree C)$			
Junction temperature	ТJ	150	\mathbb{C}
Storage Temperature Range	Tstg	-55 to +150	$^{\circ}$



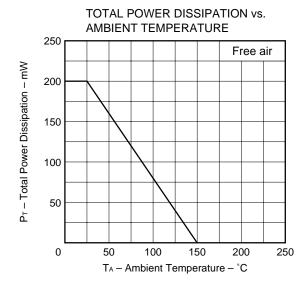
ELECTRICAL CHARACTERISTICS (TA = 25 °C)

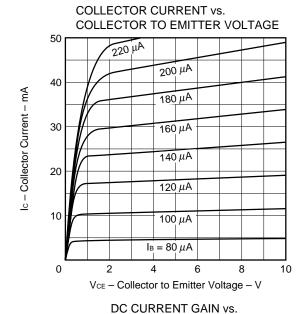
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	Ісво			100	nA	Vcb = 50 V, IE = 0
DC Current Gain	hFE1*	35	62	100		VcE = 5.0 V, Ic = 5.0 mA
DC Current Gain	hFE2*	80	230			Vce = 5.0 V, Ic = 50 mA
Collector Saturation Voltage	VcE(sat)*		0.05	0.2	V	Ic = 5.0 mA, I _B = 0.25 mA
Low-Level Input Voltage	VIL*		1.08	0.8	V	$V_{CE} = 5.0$, $I_{C} = 100 \mu A$
High-Level Input Voltage	V _{IH} *	3.0	1.4		V	Vce = 0.2 V, Ic = 5.0 mA
Input Resistor	R ₁	7.0	10	13	kΩ	
Resistor Ratio	R ₁ /R ₂	0.9	1.0	1.1		
Turn-on Time	ton		0.06	0.2	μs	Vcc = 5 V, Vin = 5 V
Storage Time	tstg		2.0	5.0	μs	$R_L = 1 \text{ k}\Omega$
Turn-off Time	toff		2.15	6.0	μs	PW = 2 μ s, Duty Cycle \leq 2 %

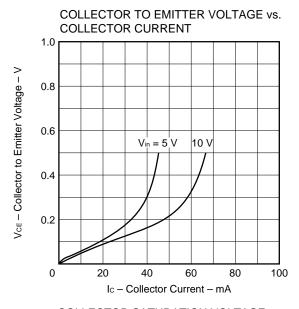
^{*} Pulsed: PW = 350 μ s, Duty Cycle = 2 %

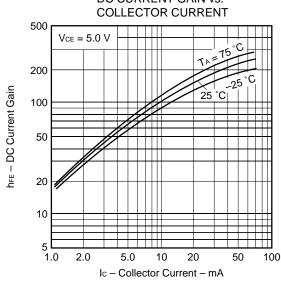


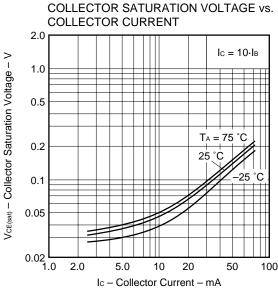
TYPICAL CHARACTERISTICS (TA = 25 °C)

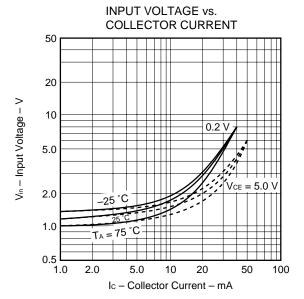




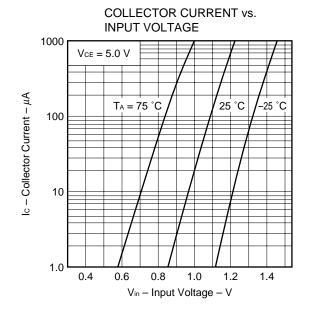


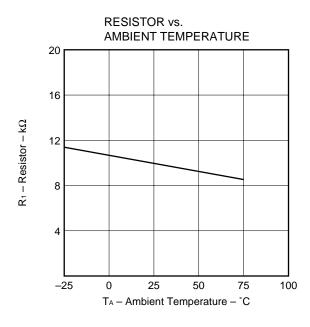


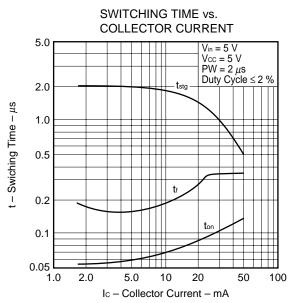












REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system	TEI-1202
Quality grade on NEC semiconductor devices	IEI-1209
Semiconductor device mounting technology manual	IEI-1207
Guide to quality assurance for semiconductor devices	MEI-1202
Semiconductor selection guide	MF-1134

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